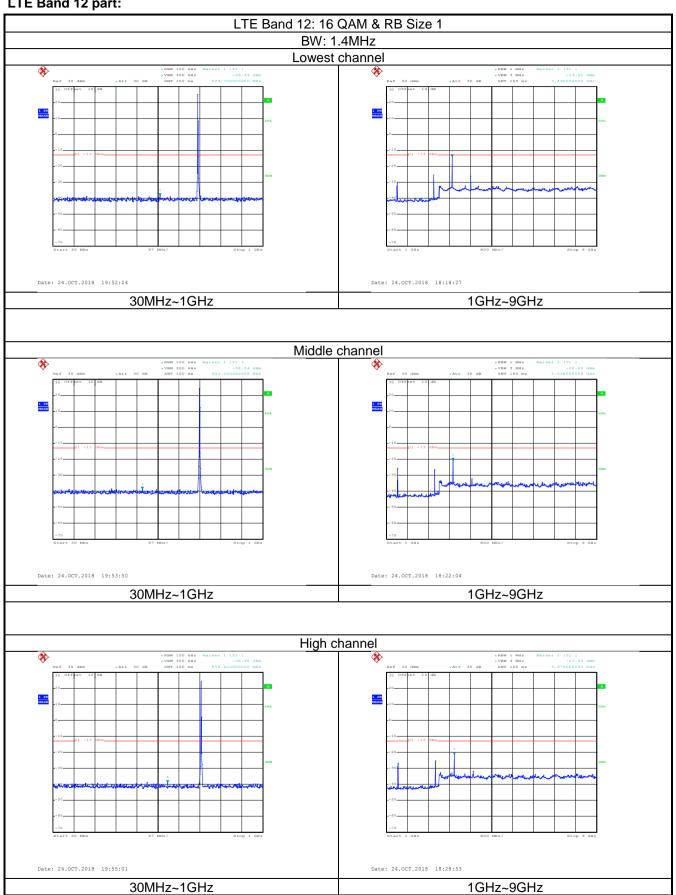




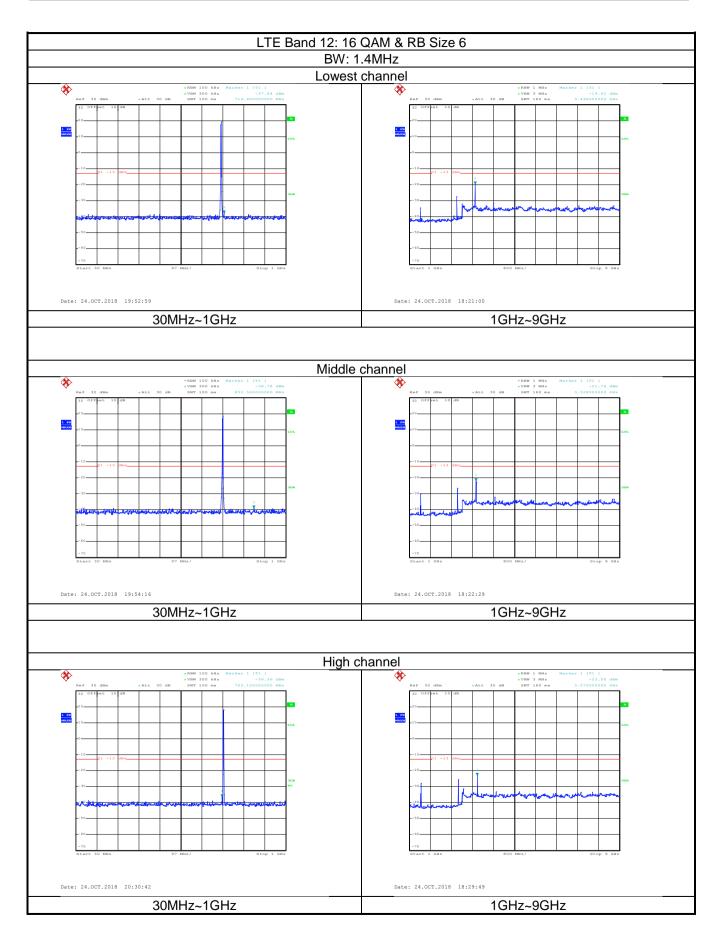


LTE Band 12 part:



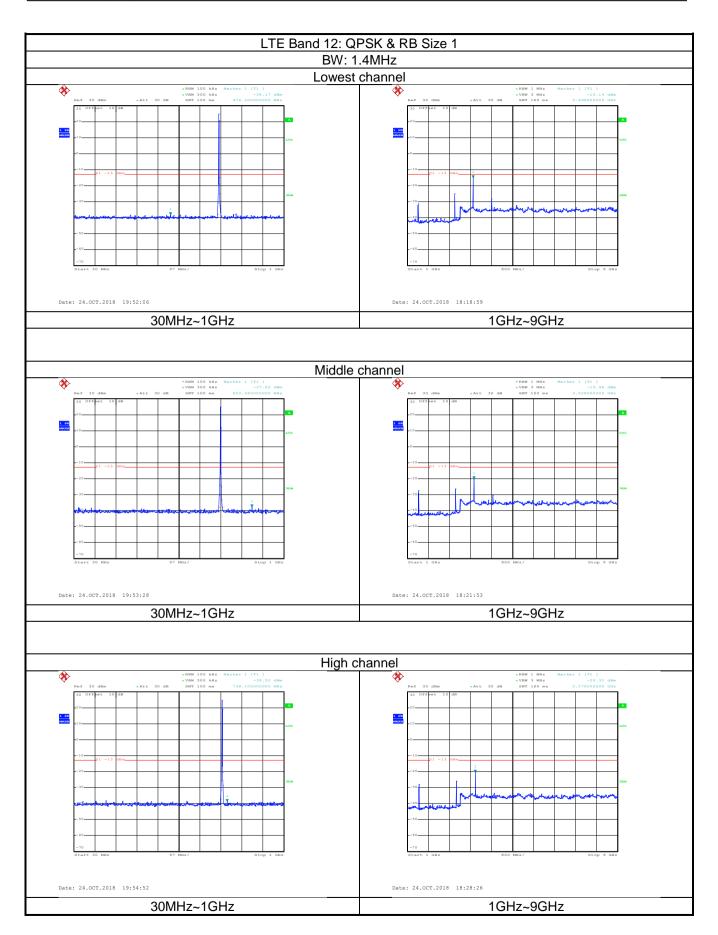






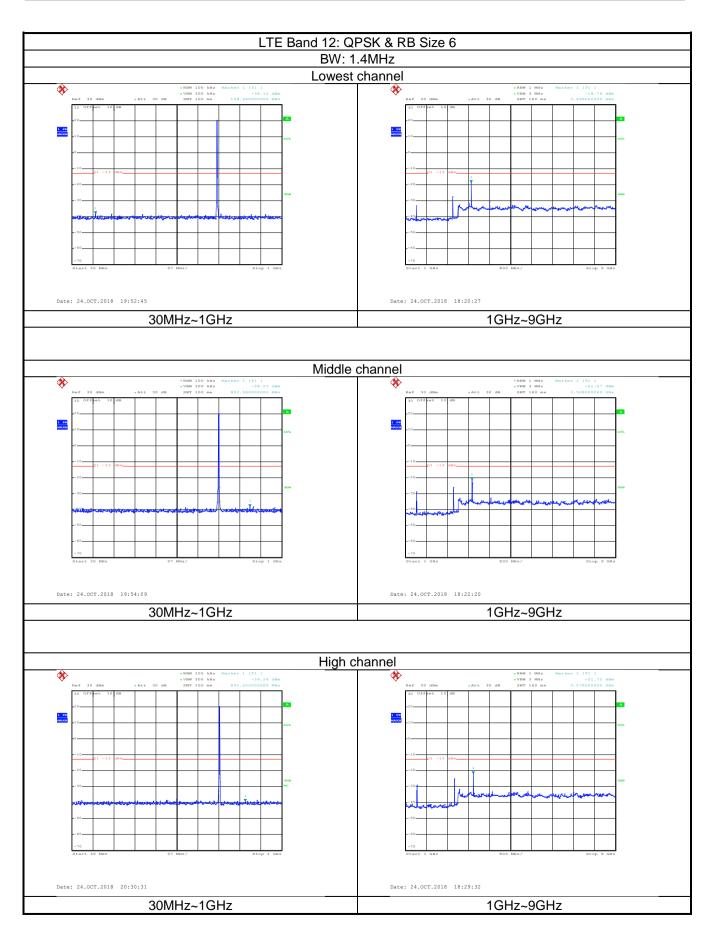






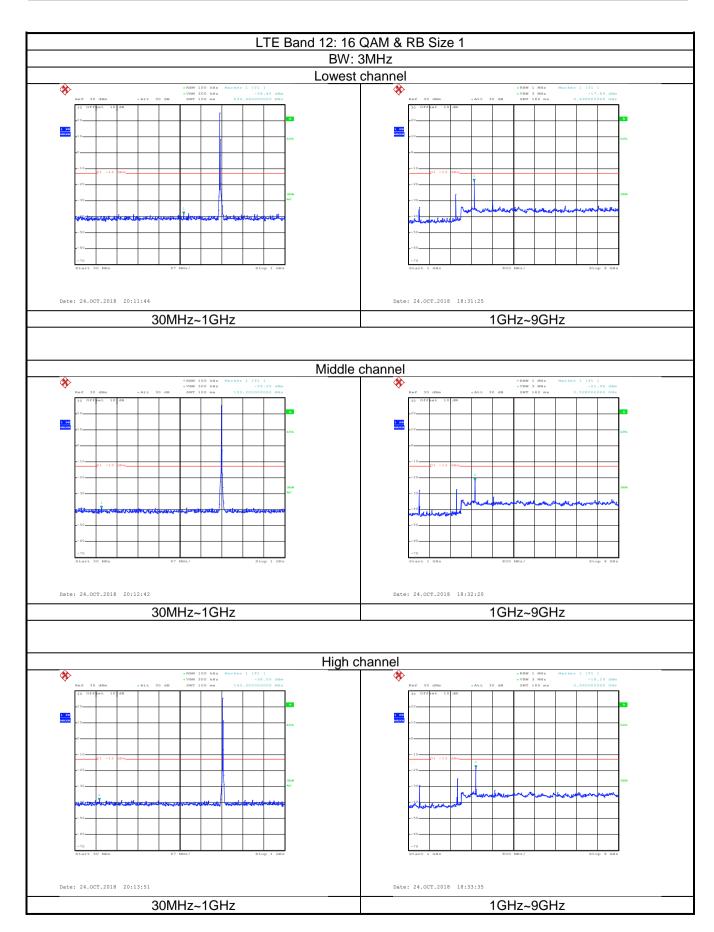






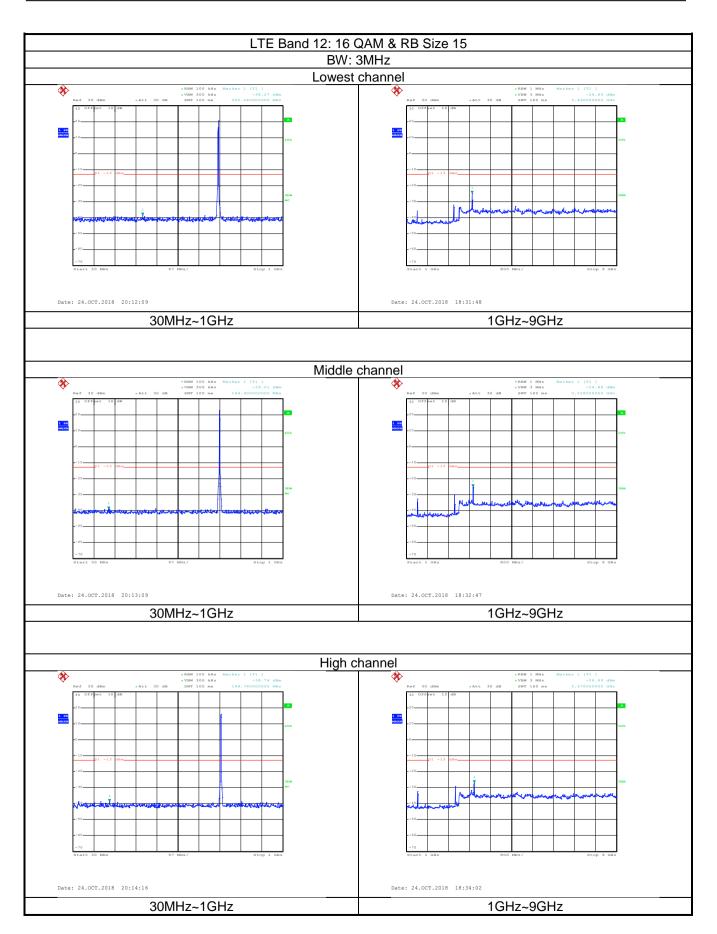






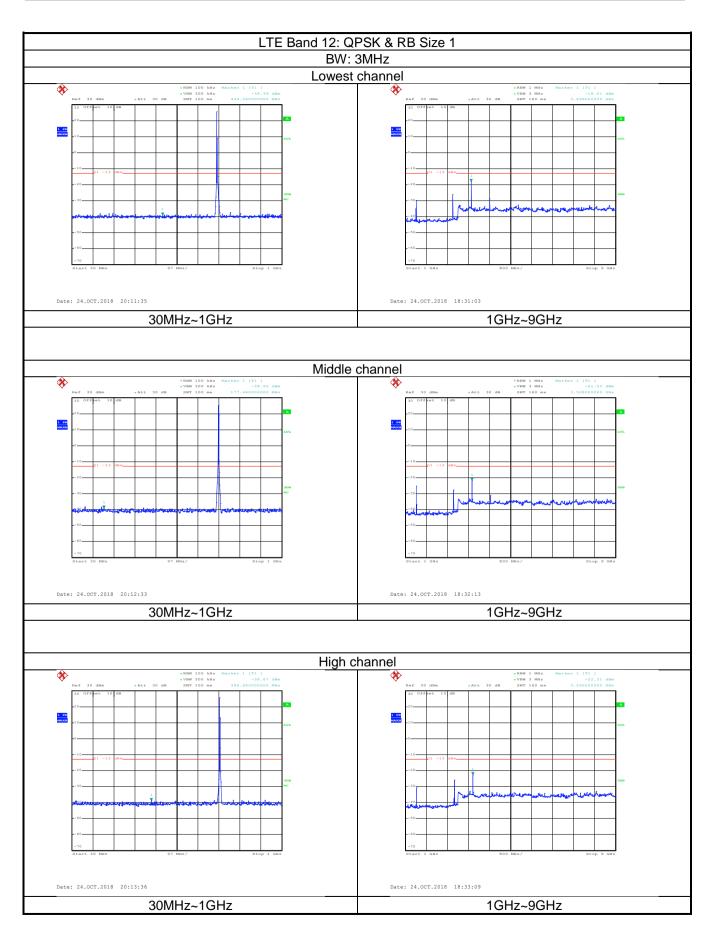






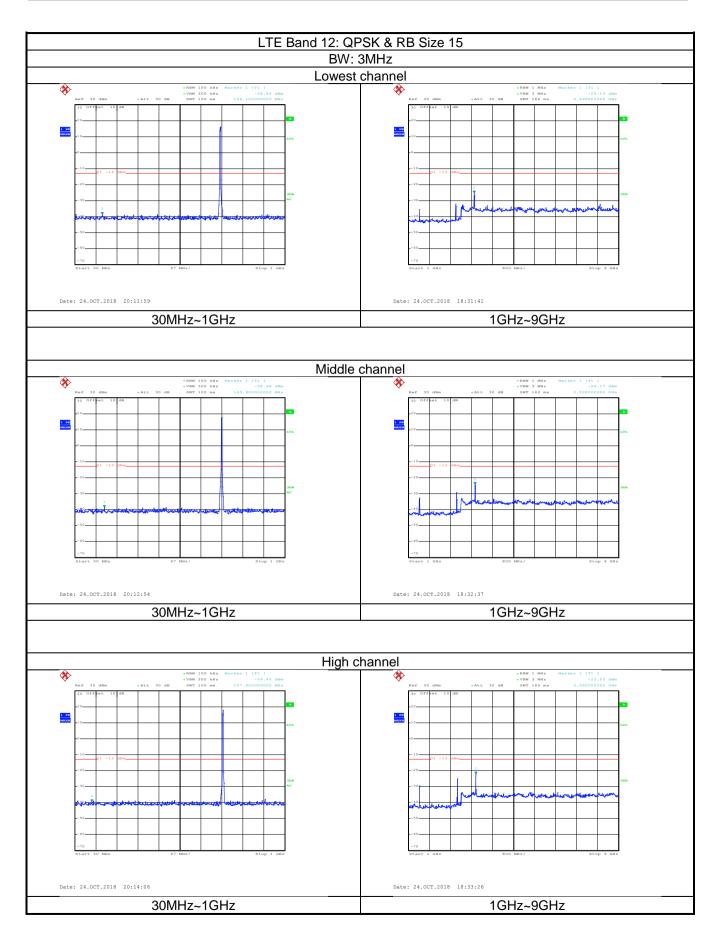






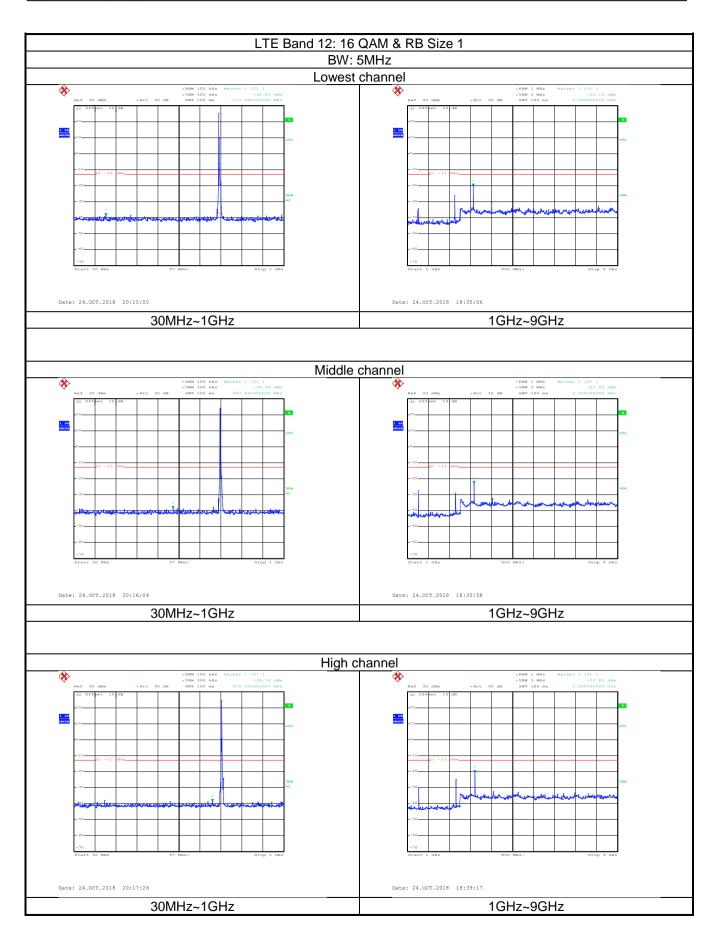






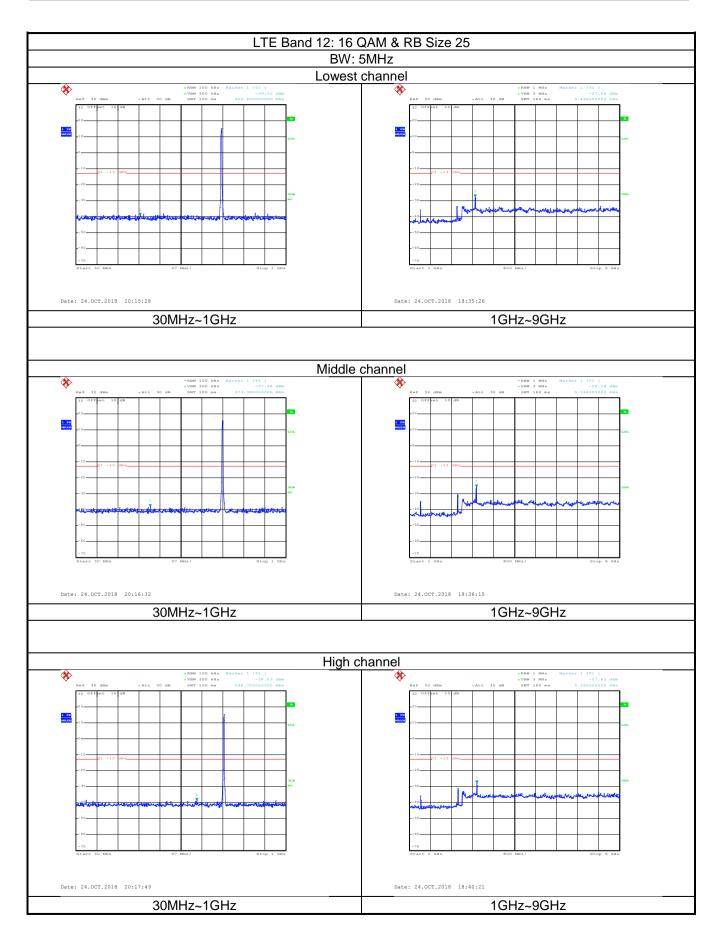






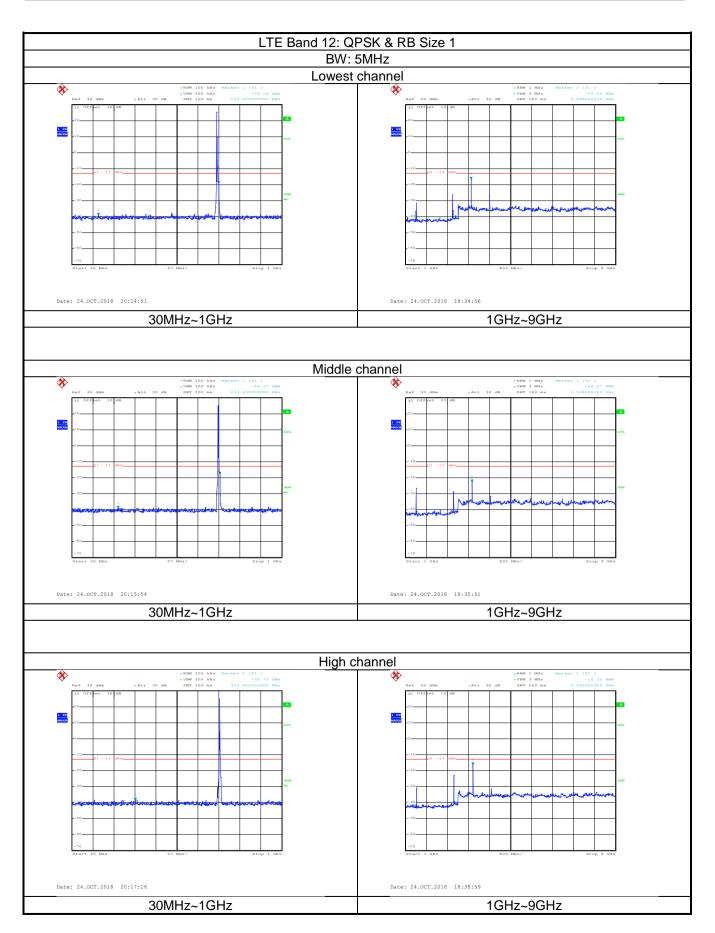






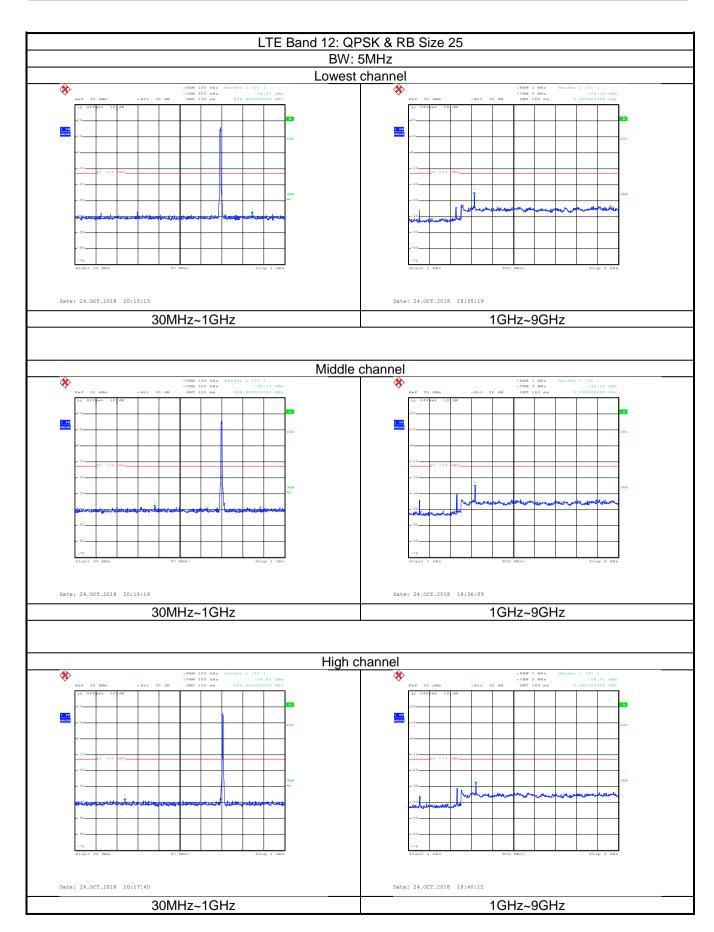






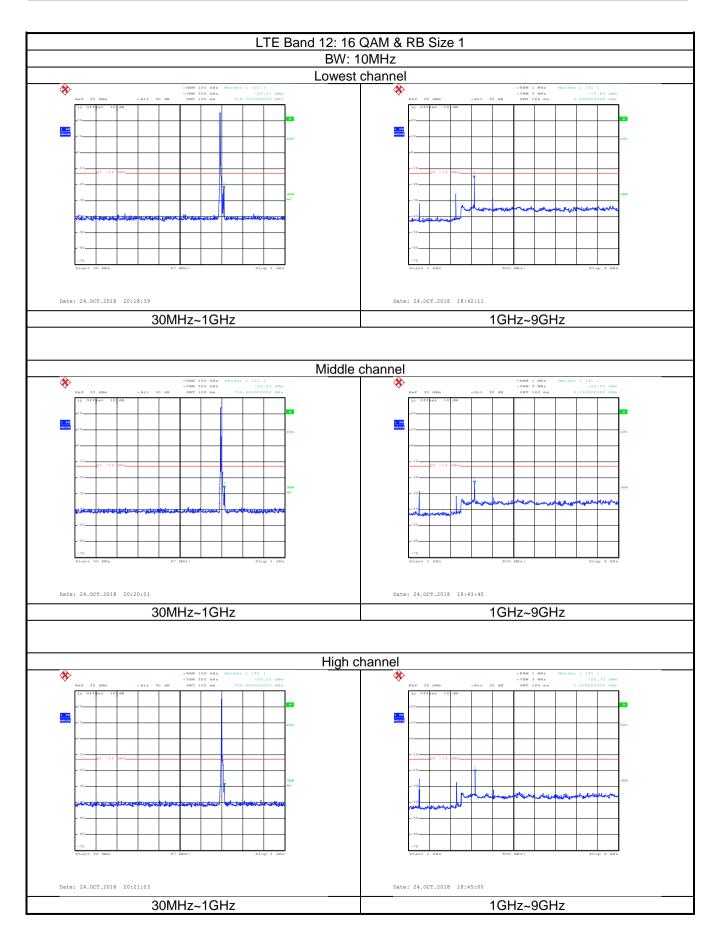






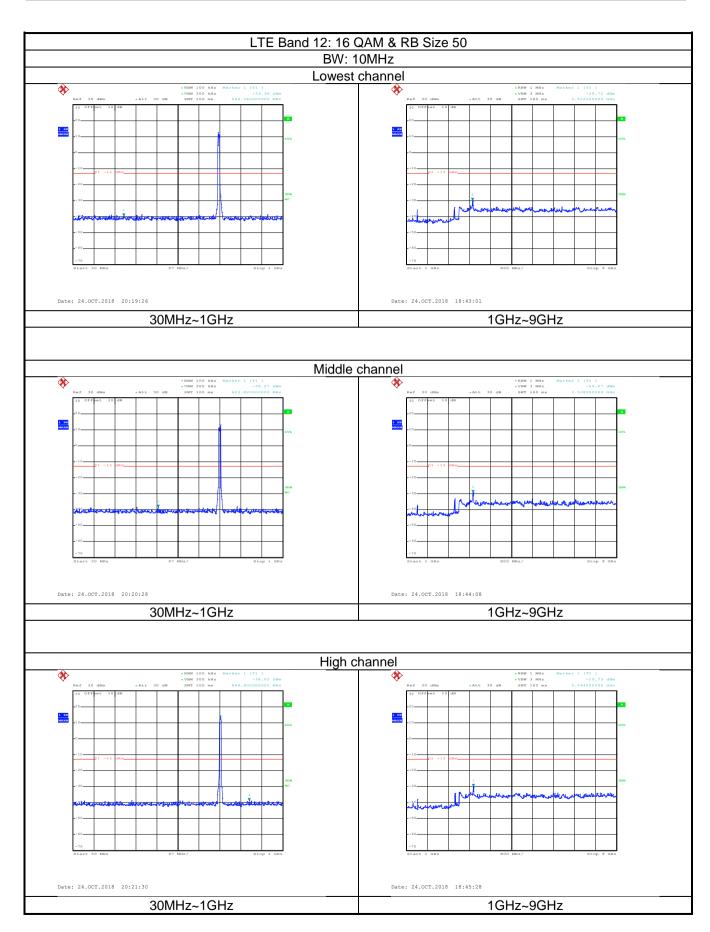






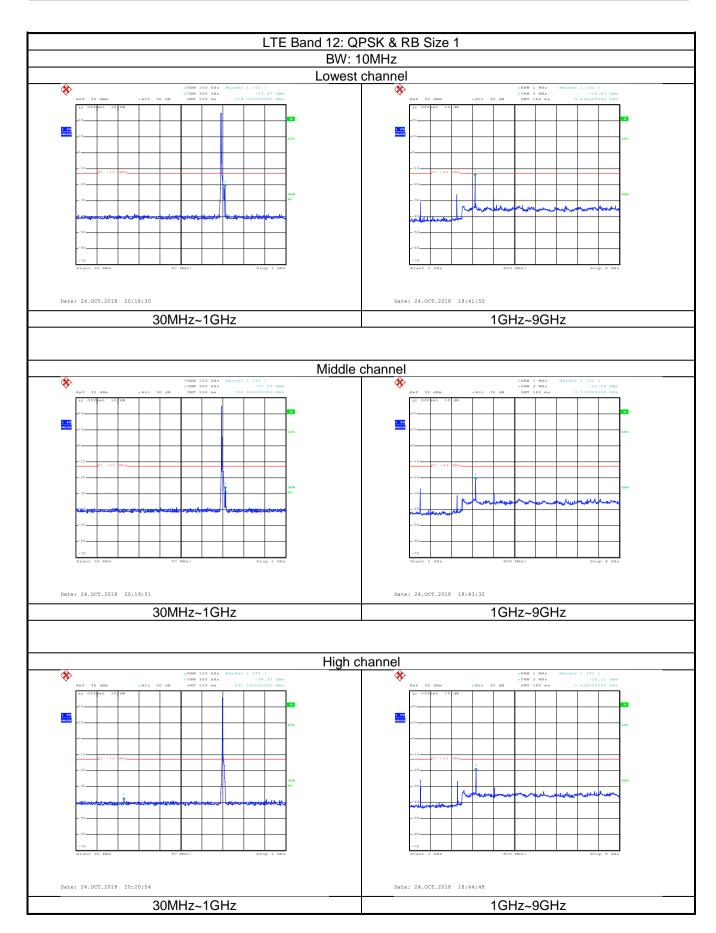






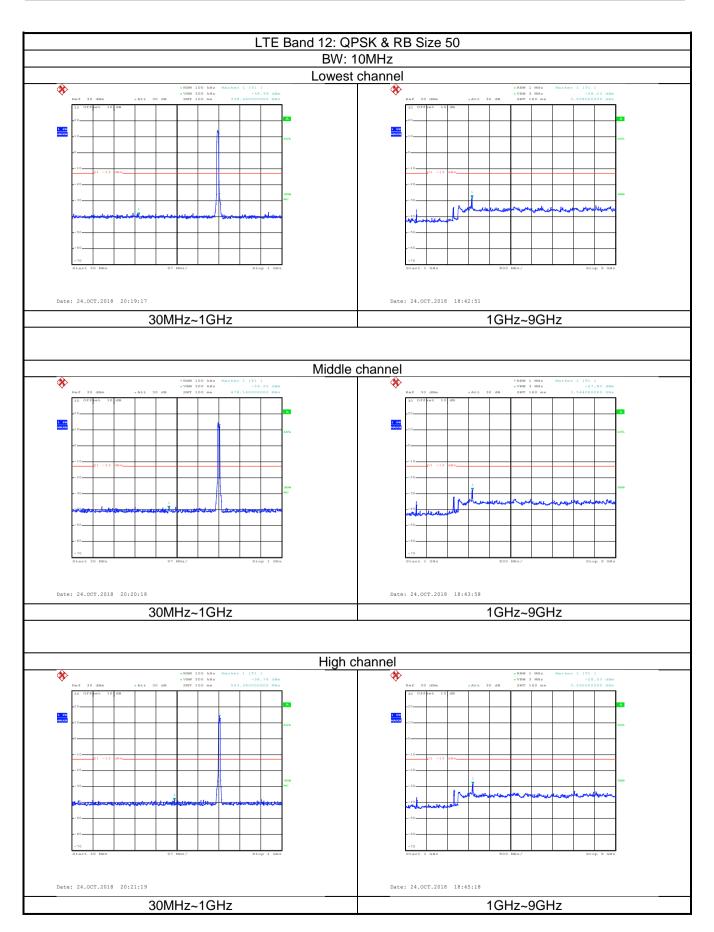










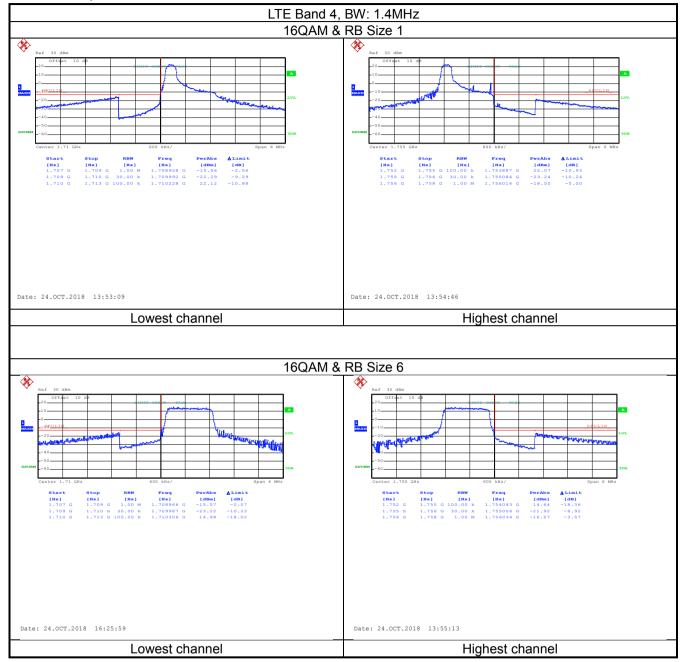






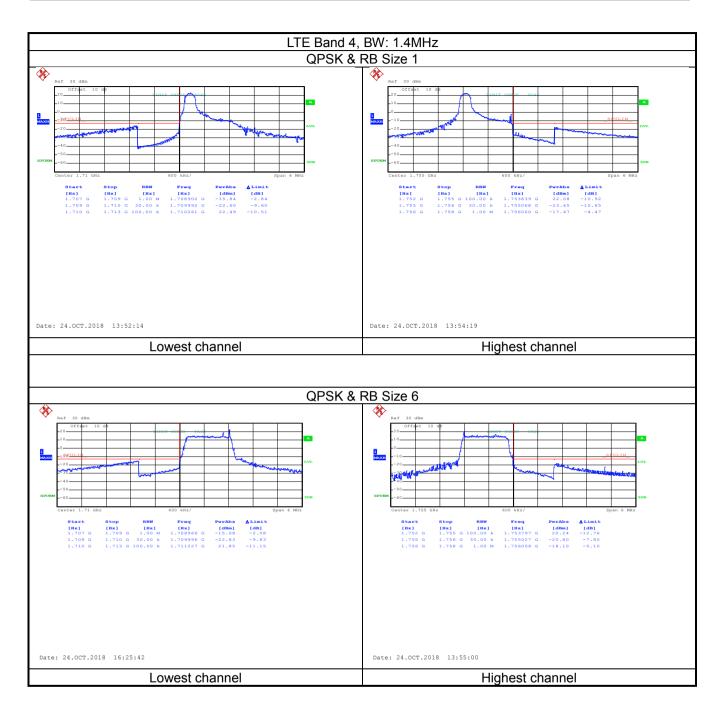
Band edge emission:

LTE Band 4 part:



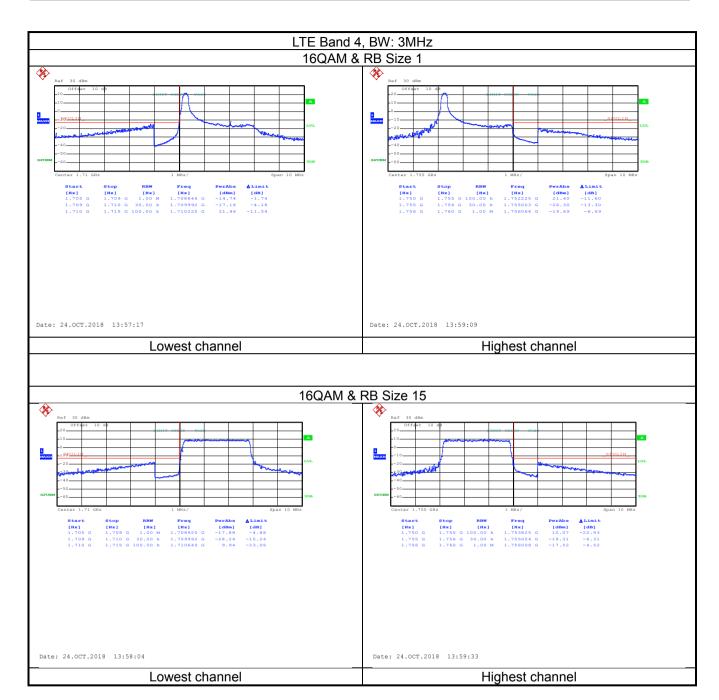






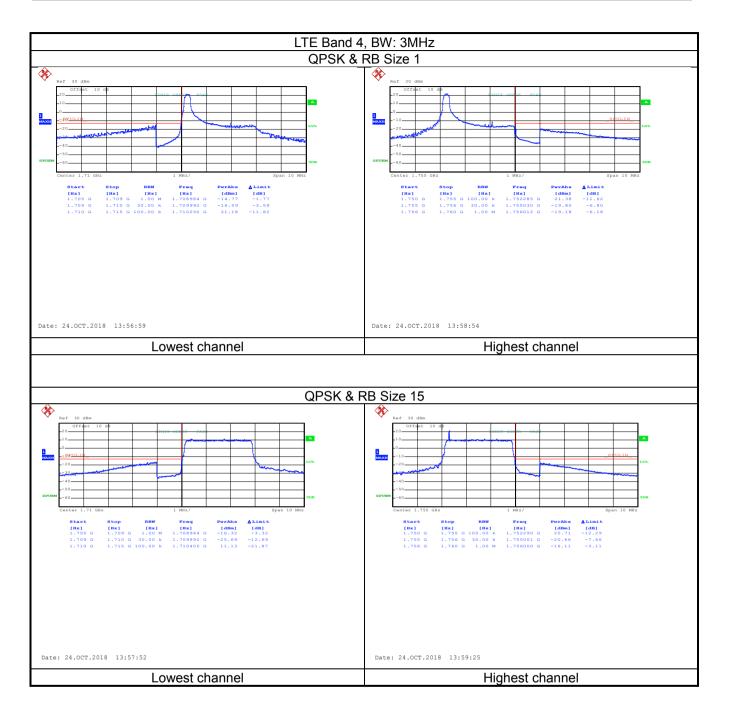






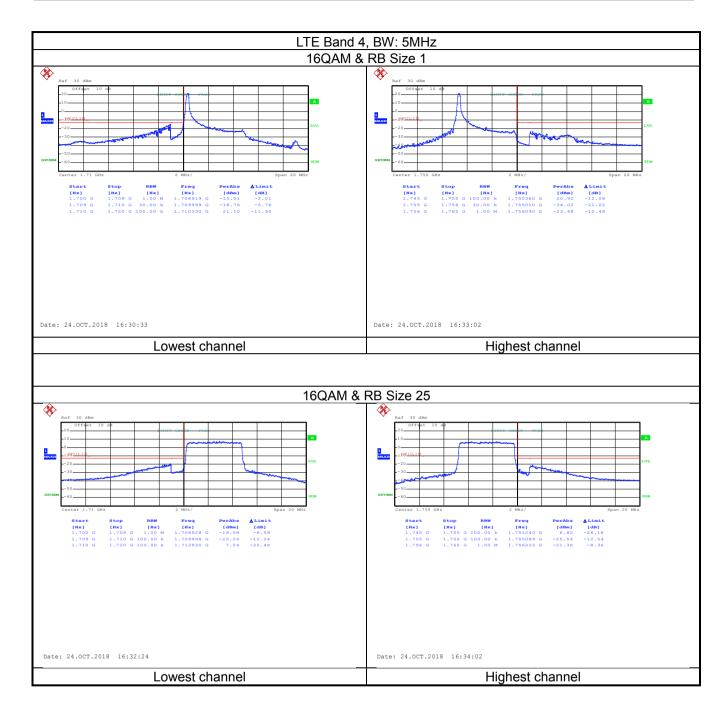






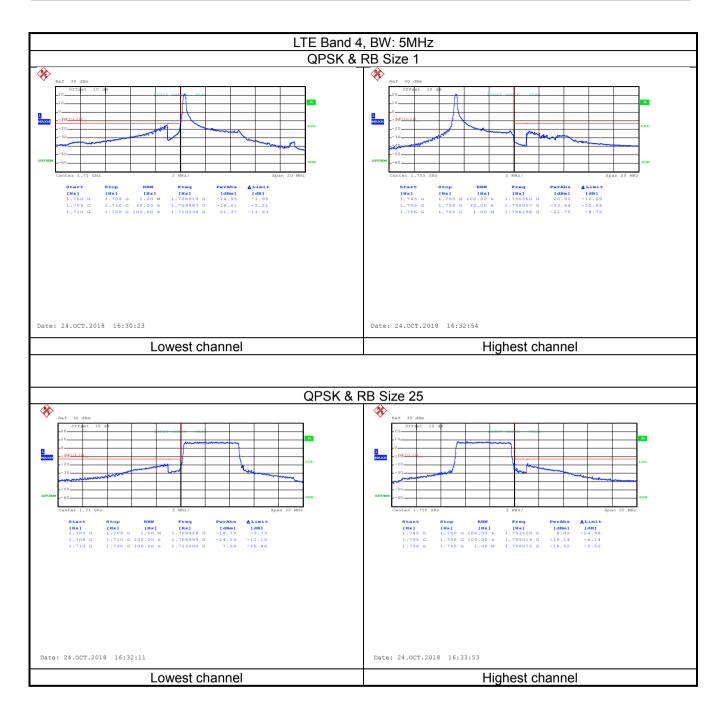






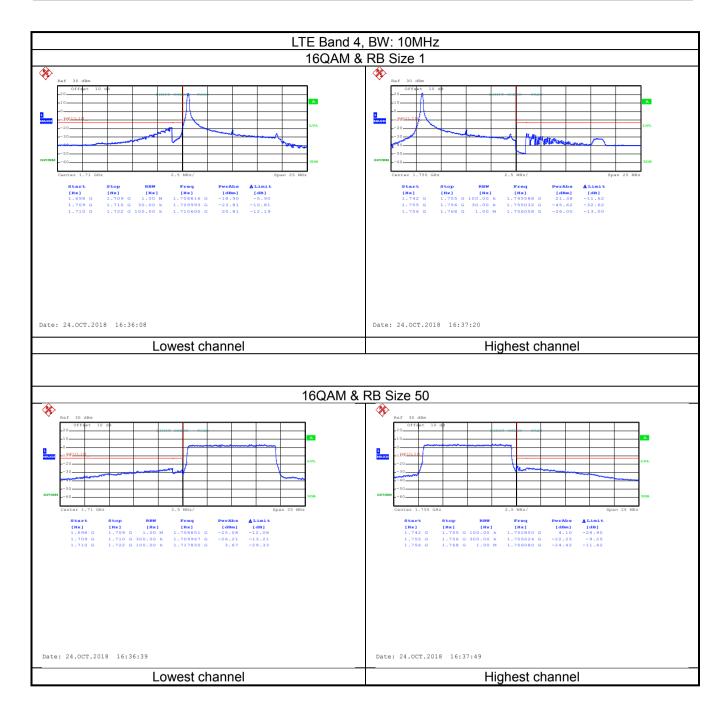






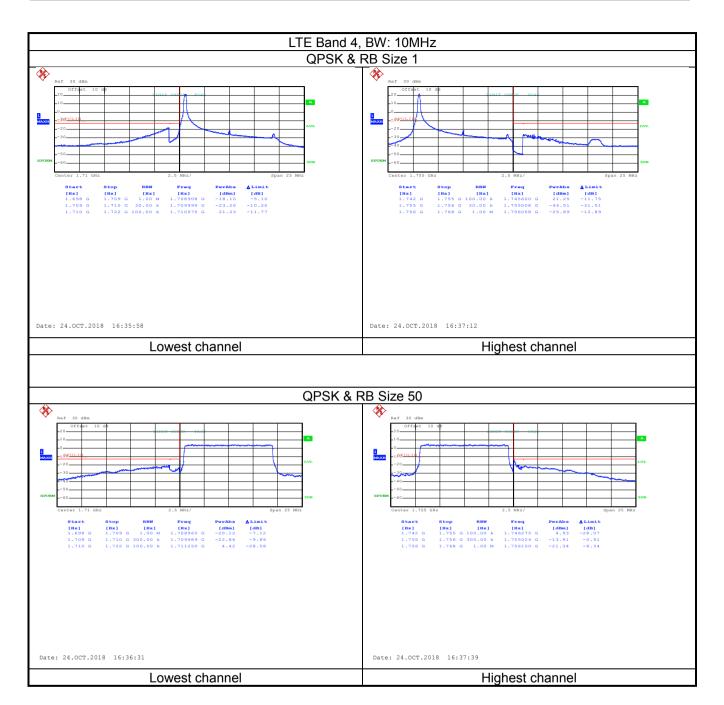






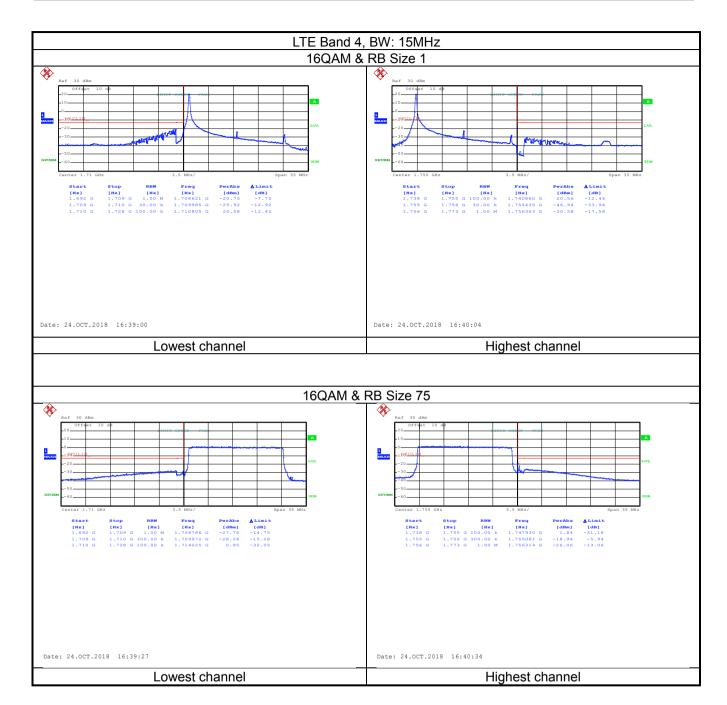






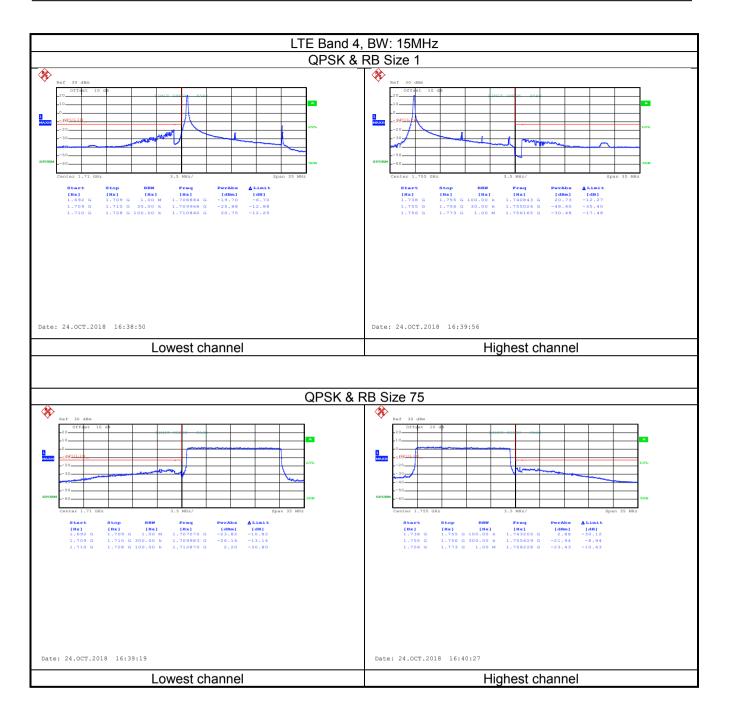






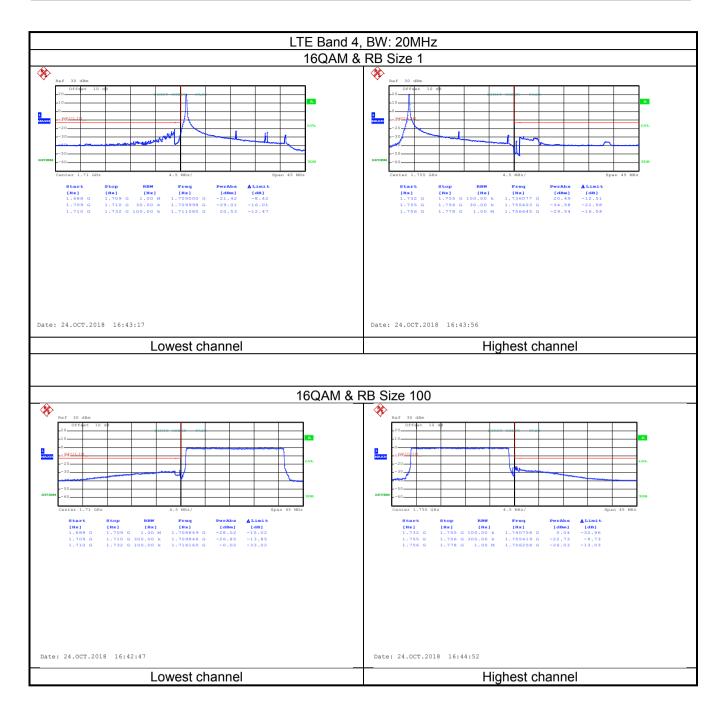






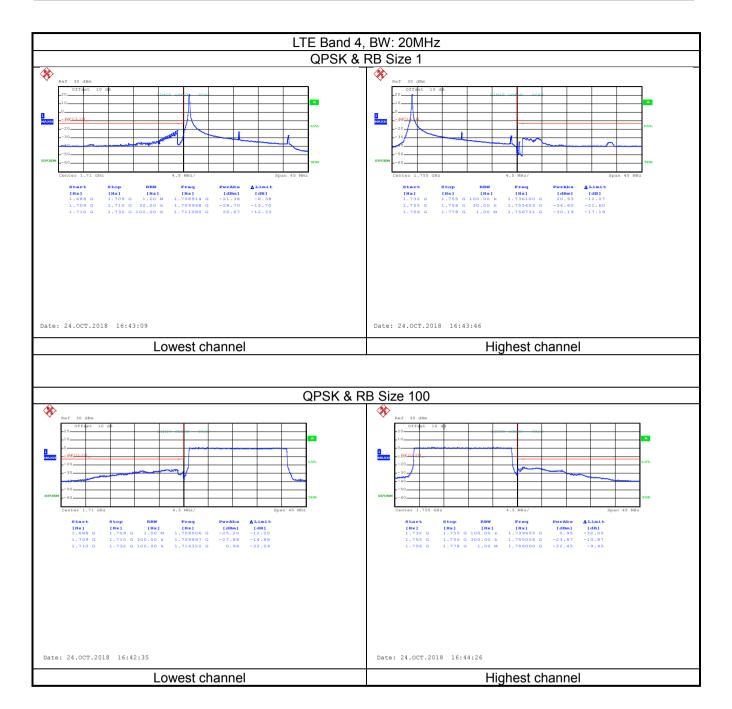








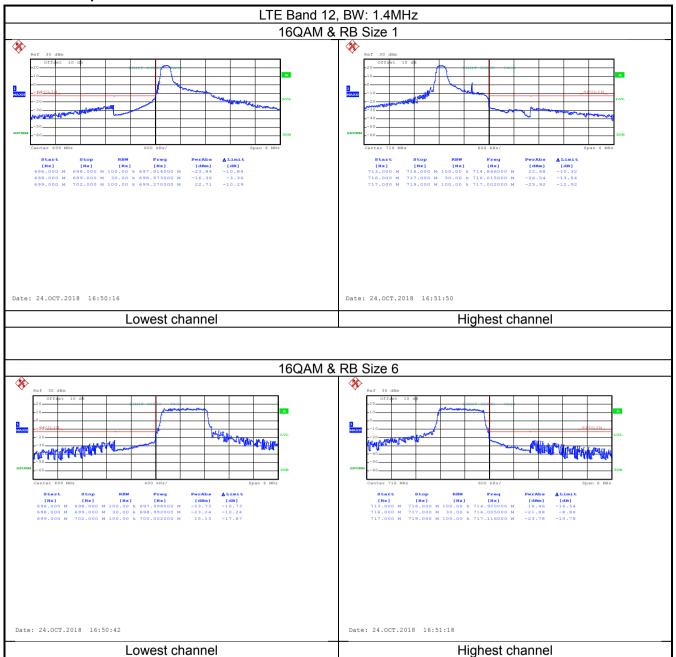






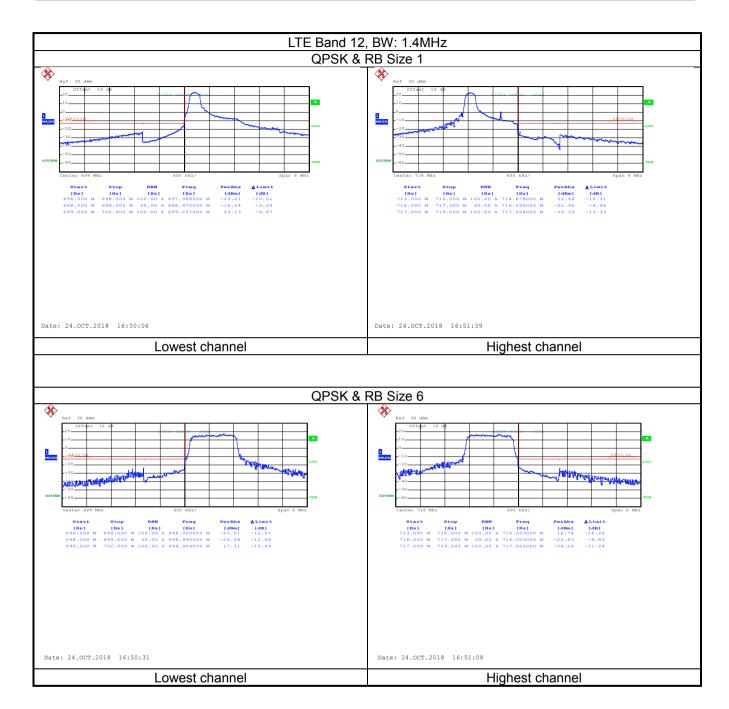


LTE band 12 part:



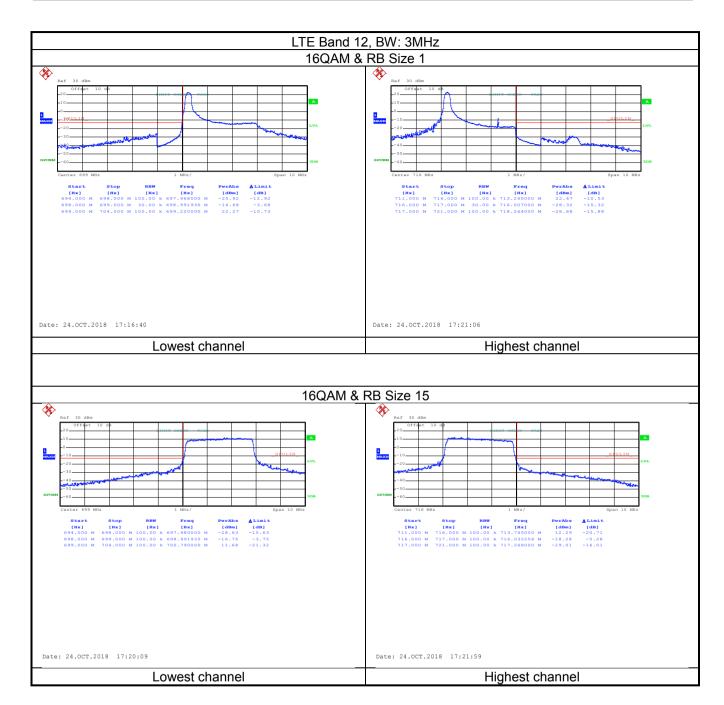






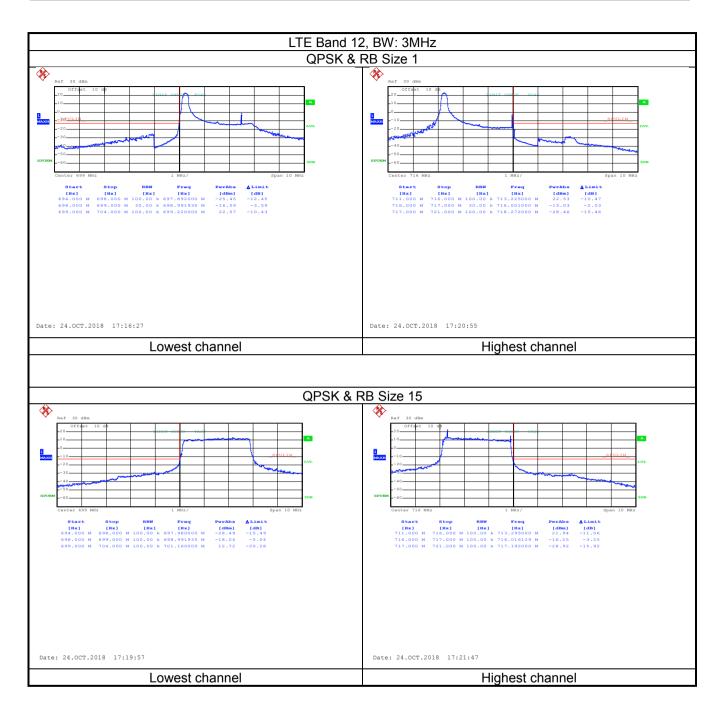






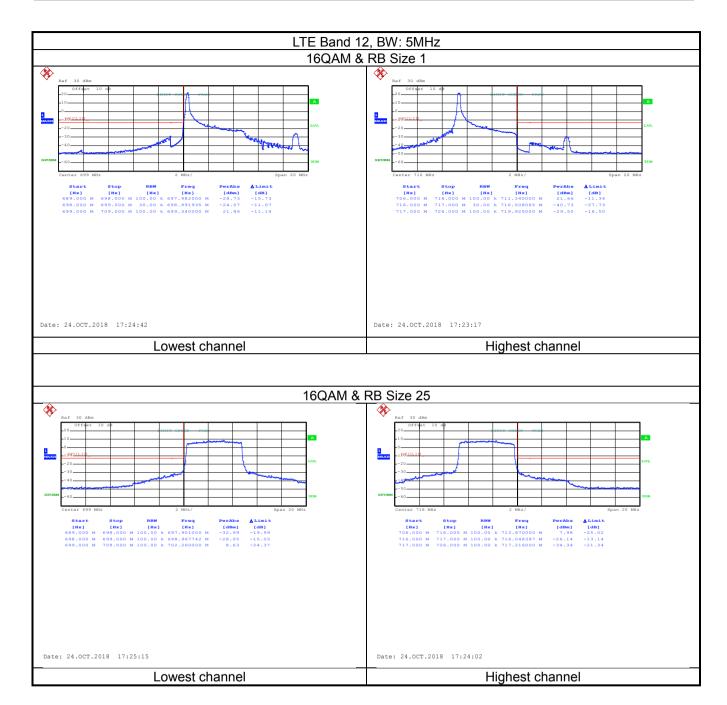






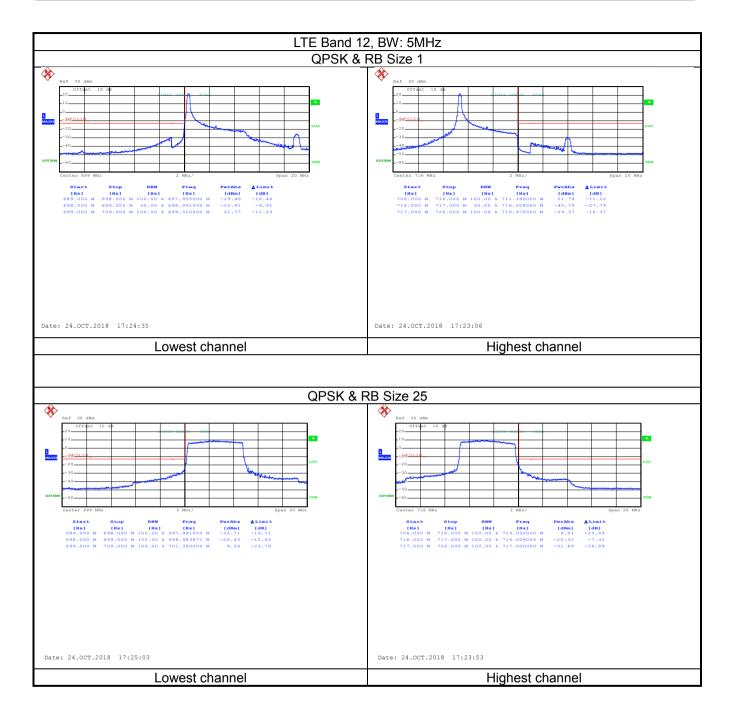






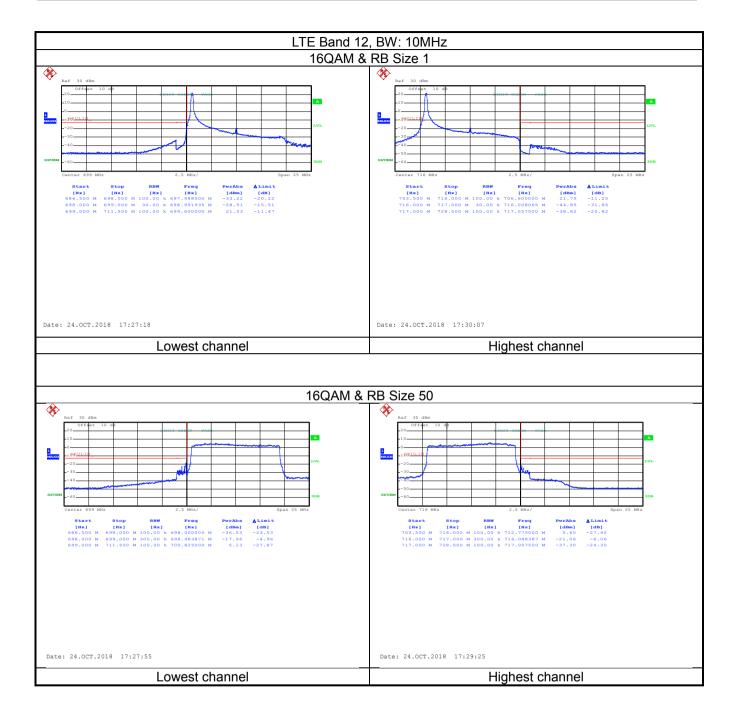






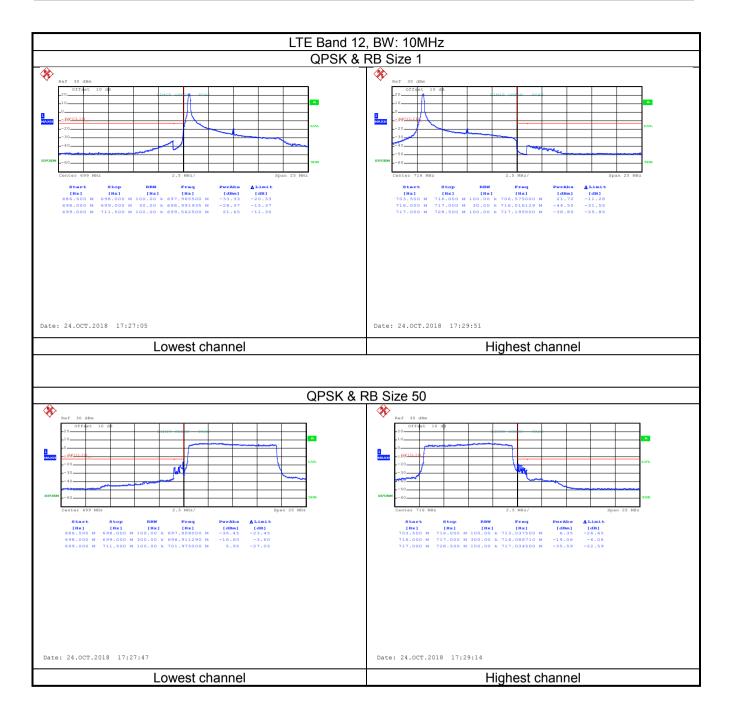














6.5 Field strength of spurious radiation measurement

	urious radiation measurement
Test Requirement:	Part 27.53(g), Part 27.53(m)
Test Method:	ANSI/TIA-603-D 2010
Limit:	LTE Band 4 & 12: The power of any emission outside a licensee's frequency block shall be attenuated below the transmitter power (P) in watts by at least 43 + 10 log ₁₀ (P) dB (-13 dBm).
Test setup:	Below 1GHz
	Antenna Tower Antenna Tower Ground Reference Plane Test Receiver Test Receiver Test Receiver
	Above 1GHz
	Antenna Tower Antenna Tower
Test Procedure:	 The EUT was placed on an non-conductive turntable using a non-conductive support. The radiated emission at the fundamental frequency was measured at 3 m with a test antenna and EMI spectrum analyzer. During the tests, the antenna height and the EUT azimuth were varied in order to identify the maximum level of emissions from the EUT. This maximization process was repeated with the EUT positioned in each of its three orthogonal orientations. The frequency range up to tenth harmonic was investigated for each of three fundamental frequency (low, middle and high channels). Once spurious emission was identified, the power of the emission was determined using the substitution method. The spurious emissions attenuation was calculated as the difference between radiated power at the fundamental frequency and the spurious emissions frequency. ERP / EIRP = S.G. output (dBm) + Antenna Gain(dB/dBi) - Cable Loss (dB)
Test Instruments:	Refer to section 5.9 for details
Test mode:	Refer to section 5.3 for details.
Test results:	Passed





Measurement Data:

LTE Band 4 part:

LTE Band 4, WB: 1.4MHz				
	RE	3 size 1 & RB offset (0	
Frequency (MHz)	Spurious E	Emission	Limit (dBm)	Result
1 requericy (ivii iz)	Polarization	Level (dBm)	Limit (dbin)	Nesuit
		Lowest Channel		
3421.40	Vertical	-45.55		
5132.10	V	-42.26		
6842.80	V	-34.67	-13.00	Pass
3421.40	Horizontal	-45.77	-13.00	Fa55
5132.10	Н	-42.80		
6842.80	Н	-35.27		
		Middle Channel		
3465.00	Vertical	-45.21		
5197.50	V	-40.71		
6930.00	V	-37.15	-13.00	Door
3465.00	Horizontal	-47.24	-13.00	Pass
5197.50	Н	-42.31		
6930.00	Н	-35.68		
		Highest Channel		
3508.60	Vertical	-43.39		
5262.90	V	-40.17		
7017.20	V	-35.00	12.00	Door
3508.60	Horizontal	-45.57	-13.00 Pa	Pass
5262.90	Н	-40.41		
7017.20	Н	-35.19		

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.





	Ľ	TE Band 4, WB: 3MHz	Z	
	R	B size 1 & RB offset ()	
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result
Frequency (MHZ)	Polarization	Level (dBm)	LIIIII (UDIII)	Result
		Lowest Channel		
3423.00	Vertical	-46.21		
5134.50	V	-43.26		
6846.00	V	-35.37	-13.00	Pass
3423.00	Horizontal	-45.92	-13.00	Pass
5134.50	Н	-42.48		
6846.00	Н	-36.37		
		Middle Channel		
3465.00	Vertical	45.36		
5197.50	V	-40.92		
6930.00	V	-38.26	-13.00	Dese
3465.00	Horizontal	-47.98	-13.00	Pass
5197.50	Н	-42.59		
6930.00	Н	-35.92		
		Highest Channel		
3507.00	Vertical	-43.42		
5260.50	V	-40.24		
7014.00	V	-35.86	12.00	Door
3507.00	Horizontal	-45.98	-13.00	Pass
5260.50	Н	-40.92		
7014.00	Н	-35.34		

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.





LTE Band 4, WB: 5MHz				
	R	B size 1 & RB offset ()	
Fraguency (MUz)	Spurious	Emission	Limit (dPm)	Result
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
		Lowest Channel		
3425.00	Vertical	-45.42		
5137.50	V	-42.26		
6850.00	V	-34.86	-13.00	Poos
3425.00	Horizontal	-45.82	-13.00	Pass
5137.50	Н	-42.98		
6850.00	Н	-35.36		
		Middle Channel		
3465.00	Vertical	-45.29		
5197.50	V	-40.87		
6930.00	V	-37.26	-13.00	Pass
3465.00	Horizontal	-47.52	-13.00	Pass
5197.50	Н	-42.39		
6930.00	Н	-35.72		
		Highest Channel		
3505.00	Vertical	-43.52		
5257.50	V	-40.24		
7010.00	V	-35.12	12.00	Door
3505.00	Horizontal	-45.61	-13.00	Pass
5257.50	Н	-40.24		
7010.00	Н	-35.26		

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.





	Lī	E Band 4, WB: 10MH	z	
	R	B size 1 & RB offset ()	
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result
Frequency (Miriz)	Polarization	Level (dBm)	Limit (ubin)	Result
		Lowest Channel		
3430.00	Vertical	-45.68		
5145.00	V	-43.26		
6860.00	V	-35.24	-13.00	Door
3430.00	Horizontal	-45.89	-13.00	Pass
5145.00	Н	-42.51		
6860.00	Н	-36.02		
		Middle Channel		
3465.00	Vertical	-45.37		
5197.50	V	-40.89		
6930.00	V	-38.24	42.00	Door
3465.00	Horizontal	-47.96	-13.00	Pass
5197.50	Н	-42.52		
6930.00	Н	-35.86		
		Highest Channel		
3500.00	Vertical	-43.36		
5250.00	V	-40.36		
7000.00	V	-35.82	42.00	Door
3500.00	Horizontal	-45.87	-13.00 Pass	Pass
5250.00	Н	-40.86		
7000.00	Н	-35.43		

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.





LTE Band 4, WB: 15MHz				
	R	B size 1 & RB offset ()	
Fraguanay (MUz)	Spurious	Emission	Limit (dPm)	Result
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
		Lowest Channel		
3435.00	Vertical	-45.26		
5152.50	V	-42.37		
6870.00	V	-34.87	-13.00	Door
3435.00	Horizontal	-45.86	-13.00	Pass
5152.50	Н	-42.34		
6870.00	Н	-35.72		
		Middle Channel		
3465.00	Vertical	-45.32		
5197.50	V	-40.93		
6930.00	V	-37.35	-13.00	Pass
3465.00	Horizontal	-47.86	-13.00	Pass
5197.50	Н	-42.31		
6930.00	Н	-35.81		
		Highest Channel		
3495.00	Vertical	-43.26		
5242.50	V	-40.24		
6990.00	V	-35.27	12.00	Door
3495.00	Horizontal	-45.86	-13.00	Pass
5242.50	Н	-40.54		
6990.00	Н	-35.36		

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.





LTE Band 4, WB: 20MHz				
	R	B size 1 & RB offset ()	
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result
Frequency (MHZ)	Polarization	Level (dBm)	LIIIII (UDIII)	Result
		Lowest Channel		
3440.00	Vertical	-45.32		
5160.00	V	-42.39		
6880.00	V	-34.83	-13.00	Door
3440.00	Horizontal	-45.98	-13.00	Pass
5160.00	Н	-42.46		
6880.00	Н	-35.79		
		Middle Channel		
3465.00	Vertical	-45.39		
5197.50	V	-40.97		
6930.00	V	-37.86	-13.00	Pass
3465.00	Horizontal	-47.92	-13.00	Pass
5197.50	Н	-42.36		
6930.00	Н	-35.81		
		Highest Channel		
3490.00	Vertical	-43.32		
5235.00	V	-40.29		
6980.00	V	-35.27	12.00	Door
3490.00	Horizontal	-45.83	-13.00	Pass
5235.00	Н	-40.59		
6980.00	Н	-35.36		

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.





LTE Band 12 part:

	LTI	E Band 12, WB: 1.4MI	Hz	
	R	B size 1 & RB offset (0	
Fraguency (MUz)	Spurious	Emission	Limit (dPm)	Result
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
		Lowest Channel		
1399.40	Vertical	-48.84		
2099.10	V	-53.81		
2798.80	V	-30.68	-13.00	Pass
1399.40	Horizontal	-49.40	-13.00	Fa55
2099.10	Н	-54.20		
2798.80	Н	-28.38		
		Middle Channel		
1415.00	Vertical	-49.26		
2122.50	V	-54.37		
2830.00	V	-32.09	-13.00	Pass
1415.00	Horizontal	-46.85	-13.00	Pass
2122.50	Н	-53.29		
2830.00	Н	-29.12		
		Highest Channel		
1430.60	Vertical	-52.02		
2145.90	V	-54.61		
2861.20	V	-31.18	12.00	Door
1430.60	Horizontal	-49.71	-13.00 Pass	Pass
2145.90	Н	-54.99		
2861.20	Н	-33.20		

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.





	L1	E Band 12, WB: 3MH	z	
	R	B size 1 & RB offset ()	
Fraguency (MHz)	Spurious	Emission	Limit (dDm)	Result
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
		Lowest Channel		
1401.00	Vertical	-48.82		
2101.50	V	-53.78		
2802.00	V	-30.63	42.00	Door
1401.00	Horizontal	-49.23	-13.00	Pass
2101.50	Н	-54.26		
2802.00	Н	-28.38		
		Middle Channel		
1415.00	Vertical	-49.34		
2122.50	V	-54.52		
2830.00	V	-32.39	42.00	Door
1415.00	Horizontal	-46.84	-13.00	Pass
2122.50	Н	-53.42		
2830.00	Н	-29.37		
		Highest Channel		
1429.00	Vertical	-52.12		
2143.50	V	-54.72		
2858.00	V	-31.36	40.00	Dana
1429.00	Horizontal	-49.86	-13.00 Pa	Pass
2143.50	Н	-55.34		
2858.00	Н	-33.64		

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.





	L1	E Band 12, WB: 5MH	z	
	R	B size 1 & RB offset ()	
Fraguenov (MHz)	Spurious	Emission	Limit (dDm)	Result
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
		Lowest Channel		
1403.00	Vertical	-48.82		
2104.50	V	-52.78		
2806.00	V	-30.20	42.00	Door
1403.00	Horizontal	-49.38	-13.00	Pass
2104.50	Н	-54.56		
2806.00	Н	-28.42		
		Middle Channel		
1415.00	Vertical	-49.32		
2122.50	V	-54.42		
2830.00	V	-32.14	42.00	Door
1415.00	Horizontal	-46.82	-13.00	Pass
2122.50	Н	-53.38		
2830.00	Н	-29.31		
<u>.</u>		Highest Channel		
1427.00	Vertical	-52.63		
2410.50	V	-54.67		
2854.00	V	-31.53	42.00	Daga
1427.00	Horizontal	-49.86	-13.00 Pas	Pass
2410.50	Н	-54.31		
2854.00	Н	-33.26		

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.





	LT	E Band 12, WB: 10MF	Ηz	
	R	B size 1 & RB offset ()	
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result
Frequency (MHZ)	Polarization	Level (dBm)	LIIIII (UDIII)	Result
		Lowest Channel		
1408.00	Vertical	-48.89		
2112.00	V	-53.98		
2816.00	V	-30.53	-13.00	Door
1408.00	Horizontal	-49.63	-13.00	Pass
2112.00	Н	-54.32		
2816.00	Н	-28.53		
		Middle Channel		
1415.00	Vertical	-48.96		
2122.50	V	-53.96		
2830.00	V	-30.56	-13.00	Pass
1415.00	Horizontal	-49.86	-13.00	Pass
2122.50	Н	-54.87		
2830.00	Н	-28.96		
·		Highest Channel		
1422.00	Vertical	-48.86		
2133.00	V	-53.97		
2844.00	V	-30.59	12.00	Door
1422.00	Horizontal	-49.64	-13.00	Pass
2133.00	Н	-54.86		
2844.00	Н	-28.89		

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.





6.6 Frequency stability V.S. Temperature measurement

Test Requirement:	Part 27.54, Part 2.1055(a)(1)(b)
Test Method:	ANSI/TIA-603-D 2010
Limit:	±2.5ppm
Test setup:	SS EUT Divider Temperature & Humidity Chamber Power Source
Test procedure:	 The equipment under test was connected to an external DC power supply and input rated voltage. RF output was connected to a frequency counter or spectrum analyzer via feed through attenuators. The EUT was placed inside the temperature chamber. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and measure EUT 25°C operating frequency as reference frequency. Turn EUT off and set the chamber temperature to -30°C. After the temperature stabilized for approximately 30 minutes recorded the frequency. Repeat step measure with 10°C increased per stage until the highest temperature of +50°C reached
Test Instruments:	Refer to section 5.9 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed





Measurement Data (worst case):

LTE Band 4 part:

Reference Fi	requency: LTE Band 4	•		5 channel=1732.5	0MHz
Power supplied (Vdc)	Temperature (°C)	Frequency error		Limit (ppm)	Result
	Tomporators (c)	Hz	ppm	Limit (ppm)	rtoouit
		QPSK		,	
	-30	198	0.114286	±2.5	Pass
	-20	136	0.078499		
3.7	-10	125	0.072150		
	0	144	0.083117		
	10	170	0.098124		
	20	188	0.108514		
	30	173	0.099856		
	40	129	0.074459		
	50	104	0.060029		
		16QAM			
	-30	190	0.109668	±2.5	Pass
3.7	-20	133	0.076768		
	-10	145	0.083694		
	0	121	0.069841		
	10	165	0.095238		
	20	174	0.100433		
	30	180	0.103896		
	40	149	0.086003		
	50	111	0.064069		





LTE Band 12 part:

Power supplied (Vdc)	Temperature (°C)	12 (10MHz) Middle channel=2309 Frequency error			
		Hz	ppm	Limit (ppm)	Result
		QPSK			
	-30	198	0.279859		Pass
	-20	133	0.187986		
	-10	136	0.192226		
	0	165	0.233216	±2.5	
3.7	10	123	0.173852		
	20	101	0.142756		
	30	145	0.204947		
	40	180	0.254417		
	50	177	0.250177		
		16QAM			
	-30	196	0.277032	±2.5	Pass
3.7	-20	123	0.173852		
	-10	165	0.233216		
	0	188	0.265724		
	10	145	0.204947		
	20	171	0.241696		
	30	102	0.144170		
	40	122	0.172438		
	50	166	0.234629		





6.7 Frequency stability V.S. Voltage measurement

Test Requirement:	Part 27.54, Part 2.1055(d)(2)			
Test Method:	ANSI/TIA-603-D 2010			
Limit:	±2.5ppm			
Test setup:	SS EUT Divider Temperature & Humidity Chamber			
Test procedure:	 Set chamber temperature to 25°C. Use a variable DC power source to power the EUT and set the voltage to rated voltage. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and recorded the frequency. Reduce the input voltage to specify extreme voltage variation (+/-15%) and endpoint, record the maximum frequency change. 			
Test Instruments:	Refer to section 5.9 for details			
Test mode:	Refer to section 5.3 for details			
Test results:	Passed			





Measurement Data (worst case):

LTE Band 4 part:

Reference Fr	equency: LTE Band	4(10MHz) Middle	channel=20175	channel=1732.	50MHz
Temperature (°C)	Power supplied	Frequency error		Limit (nnm)	Result
	(Vdc)	Hz	ppm	Limit (ppm)	Kesuit
		QPSK			
	4.2	99	0.057143	±2.5	Pass
25	3.7	88	0.050794		
	3.5	74	0.042713		
		16QAM			
25	4.2	80	0.046176	±2.5	Pass
	3.7	96	0.055411		
	3.5	77	0.044444		
Note: Only the worst ca	se shown in the report.				

LTE Band 12 part:

Reference Fr	equency: LTE Band	12(10MHz) Midd	lle channel=2309	5 channel=707.5	0MHz
Temperature (°C)	Power supplied	Frequency error		Limit (mmm)	Dagult
	(Vdc)	Hz	ppm	Limit (ppm)	Result
		QPSK			
	4.2	98	0.138516		Pass
25	3.7	90	0.127208	±2.5	
	3.5	63	0.089046		
		16QAM		·	
25	4.2	84	0.118728	±2.5	Pass
	3.7	75	0.106007		
	3.5	63	0.089046		